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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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MULTIPLE (QUAD) NPN SILICON DUAL IN-LINE AND FLATPACK SWITCHING TRANSISTOR

Qualified per MIL-PRF-19500/559

Devices

2N6989 2N6989U

2N6990

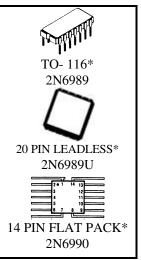
Qualified Level

JAN JANTX JANTXV JANS

MAXIMUM RATINGS (1)

Ratings	Symbol	Value	Units
Collector-Emitter Voltage (3)	V_{CEO}	50	Vdc
Collector-Base Voltage (3)	V_{CBO}	75	Vdc
Emitter-Base Voltage (3)	V_{EBO}	6.0	Vdc
Collector Current (3)	$I_{\rm C}$	800	mAdc
Total Power Dissipation @ $T_A = +25^{0}C$ $2N6989^{(2)}$ $2N6989U^{(2)}$ $2N6990^{(2)}$	P _D	1.5 1.0 0.4	W
Operating & Storage Junction Temperature Range	Top, Tstg	-65 to +200	°C

- 1) Maximum voltage between transistors shall be ≥ 500 Vdc
- 2) Derate linearly 8.57 mW/ 0 C above $T_{A} = +25^{0}$ C for 2N6989 and 2N6989U Derate linearly 2.286 mW/ 0 C above $T_{A} = +25^{0}$ C for 2N6990 Ratings apply to total package.
- 3) Ratings apply to each transistor in the array.



*See appendix A for package outline

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}$ C unless otherwise noted)

Characteristics	Symbol	Min.	Max.	Unit
OFF CHARACTERISTICS				
Collector-Emitter Breakdown Voltage	V	50		Vdc
$I_C = 10 \text{ mAdc}$	$V_{(BR)CEO}$	30		vuc
Collector-Base Cutoff Current				
$V_{CB} = 60 \text{ Vdc}$	I_{CBO}		10	ηAdc
$V_{CB} = 75 \text{ Vdc}$; $I_c = 10 \mu \text{Adc}$			10	μAdc
Emitter-Base Cutoff Current				
$V_{EB} = 4.0 \text{Vdc}$	I_{EBO}		10	ηAdc
$V_{EB} = 6.0 \text{Vdc}$; $I_c = 10 \mu\text{Adc}$			10	μAdc

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2N6989, 2N6990 JAN, SERIES

ELECTRICAL CHARACTERISTICS (con't)

Characteristics	Symbol	Min.	Max.	Unit
ON CHARACTERISTICS (4)				
Forward-Current Transfer Ratio				
$I_C = 0.1 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}$		50		
$I_C = 1.0 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}$		75	325	
$I_C = 10 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}$	$h_{ m FE}$	100	323	
$I_C = 150 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}$		100	300	
$I_C = 500 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}$		30		
Collector-Emitter Saturation Voltage				
$I_C = 150 \text{ mAdc}, I_B = 15 \text{ mAdc}$	V _{CE(sat)}		0.3	Vdc
$I_C = 500 \text{ mAdc}, I_B = 50 \text{ mAdc}$			1.0	
Base-Emitter Saturation Voltage				
$I_C = 150 \text{ mAdc}, I_B = 15 \text{ mAdc}$	$V_{\mathrm{BE}(\mathrm{sat})}$	0.6	1.2	Vdc
$I_C = 500 \text{ mAdc}, I_B = 50 \text{ mAdc}$			2.0	
DYNAMIC CHARACTERISTICS				
Magnitude of Small-Signal Short-Circuit		2.5	8.0	
Forward Current Transfer Ratio	$ h_{\mathrm{fe}} $			
$I_C = 20 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}, f = 100 \text{ MHz}$				
Forward Current Transfer Ratio	h	50		
$I_C = 1.0 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}, f = 1.0 \text{ kHz}$	h _{fe}			
Output Capacitance	C		8.0	pF
$V_{CB} = 10 \text{ Vdc}, I_E = 0, 100 \text{ kHz} \le f \le 1.0 \text{ MHz}$	C_{obo}			
Input Capacitance	C	C _{ibo}	25	pF
$V_{EB} = 0.5 \text{ Vdc}, I_E = 0, 100 \text{ kHz} \le f \le 1.0 \text{ MHz}$	Cibo			

⁽⁴⁾ Pulse Test: Pulse Width = 300μ s, Duty Cycle $\leq 2.0\%$.